N-Channel 150-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
150	700 @ V _{GS} = 10V	1.2	
	1200 @ V _{GS} = 4.5V	1	

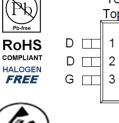
TSOP-6

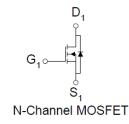
Top View

6 🗖 D

5 🗖 D

4 🗖 S







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	150	V	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current ^a	T _A =25°C	I_	1.2		
Continuous Drain Current	T _A =70°C	I _D	1	А	
Pulsed Drain Current ^b			±10		
Continuous Source Current (Diode Conduction) ^a		I _S	2.5	А	
Power Dissinction ^a	T _A =25°C	P _D	2	W	
Power Dissipation ^a	T _A =70°C	гD	1.3	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter			Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	R _{eja}	62.5	°C/W	
	Steady State	ιν _θ ja	110	C/W	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

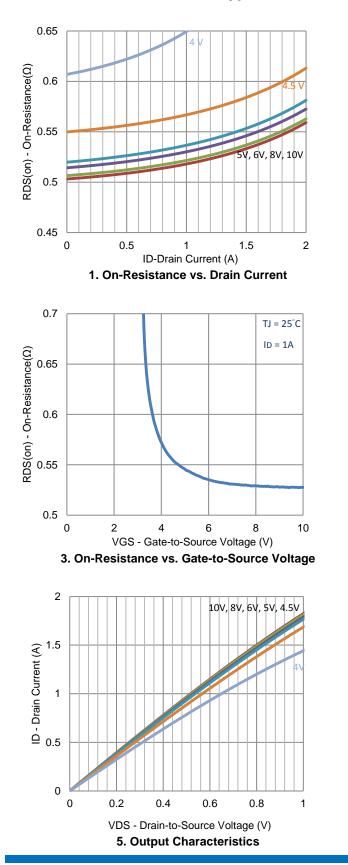
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1		3.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	uA	
Zero Gate Voltage Drain Current		$V_{DS} = 120 V, V_{GS} = 0 V$			1	u A	
	IDSS	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	1			А	
Drain-Source On-Resistance	r.	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.2 \text{ A}$			700	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 1 \text{ A}$			1200	11122	
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 1.2 \text{ A}$		5		S	
Diode Forward Voltage	V_{SD}	I _S = 1.25 A, V _{GS} = 0 V		0.8		V	
		Dynamic					
Total Gate Charge	Qg			2.5			
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 1 \text{ A}$		1		nC	
Gate-Drain Charge	Q_gd			0.8			
Turn-On Delay Time	t _{d(on)}			5			
Rise Time	t _r	$\begin{split} V_{\text{DD}} &= 10 \text{ V}, \text{R}_{\text{L}} = 10 \Omega, \text{I}_{\text{D}} = 1 \text{ A}, \\ V_{\text{GEN}} &= 10 \text{ V}, \text{R}_{\text{GEN}} = 6 \Omega \end{split}$		8		ns	
Turn-Off Delay Time	t _{d(off)}			20			
Fall Time	t _f			10			
Input Capacitance	C _{iss}			320			
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		37		pF	
Reverse Transfer Capacitance	C _{rss}			20			

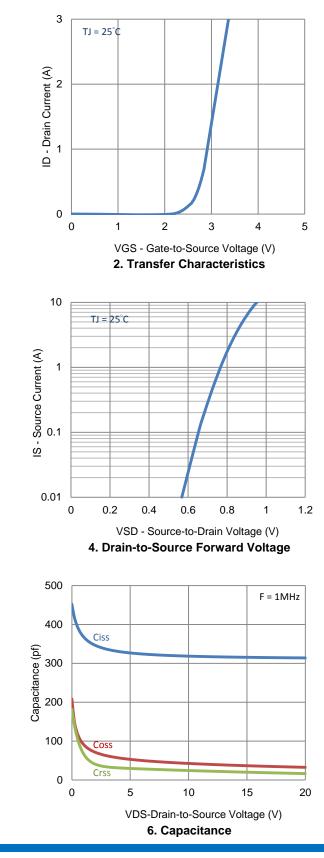
Notes

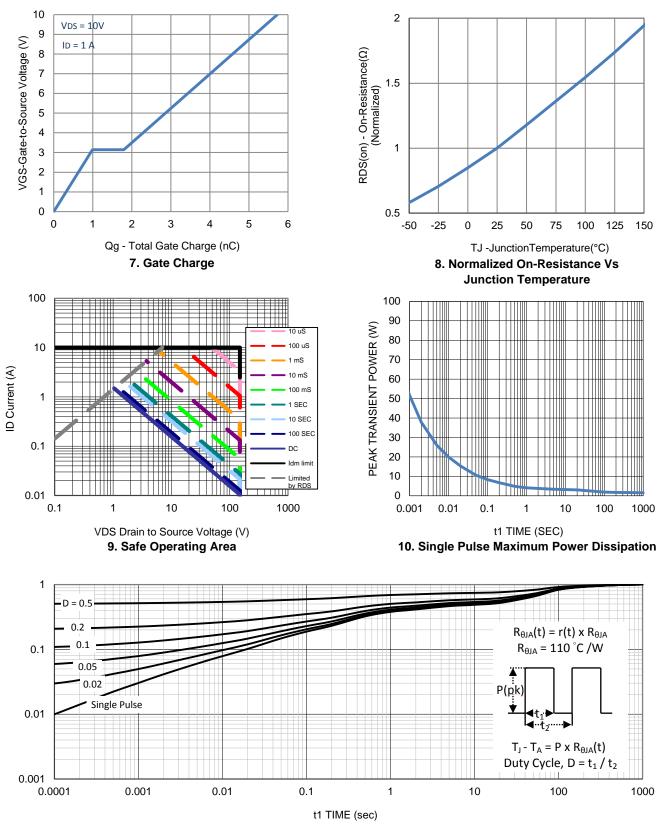
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics

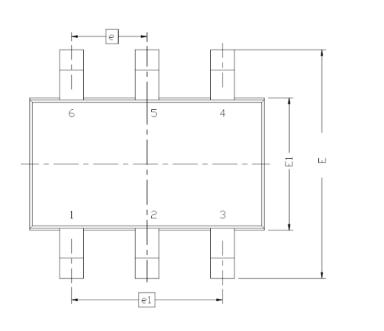




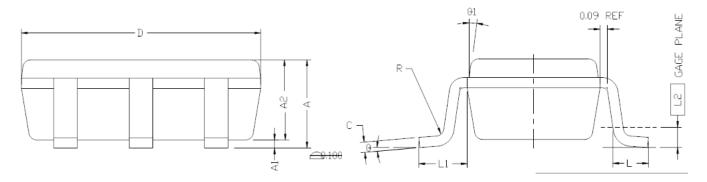
Typical Electrical Characteristics

11. Normalized Thermal Transient Junction to Ambient

Package Information



DIM.	MIL	RS	
DIM.	MIN	MIN NDM	
Α	0.935		1.10
A1	0.01		0.10
A2	0.70		1.00
b	0.25	0.32	0.40
\subset	0.10	0.15	0.20
D	2.95	3.05	3.10
E	2.70	2.85	2.98
E1	1.55	1.65	1.70
е	0	.95 BS	C
L	0.30		0.60
L1	0.60REF		
L2	0.25BSC		
R	0.10		
θ	0?	4?	8?
θ1		7? NOM	1



Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- 5. Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.

Ordering Information

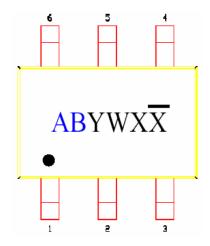
• AM3490NE-T1-XX

– T1:

- A: Analog Power
- M: MOSFET
- 3490: Part number
- N: N-Channel
- E: ESD Protection
 - Tape & reel
- XX: Blank: Standard
 - PF: Leadfree

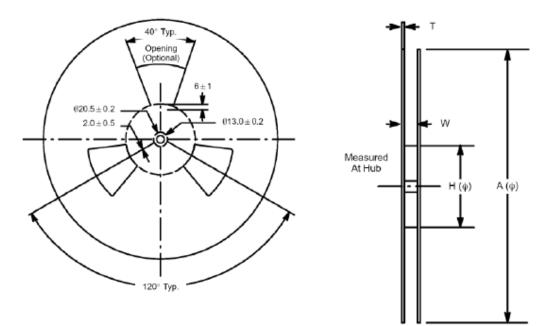
Part Marking

- Line 1: Part Number/Trace Code (Example: ABYWXX)
 - AB: Part Number code
 - Y: Year Code
 - W: Month Code
 - $X\overline{X}$: Lot Code
 - Pb-Free Product Laser Mark: Add Bar Over Lot Code "X"



Tape & Reel Information

LOK REEL



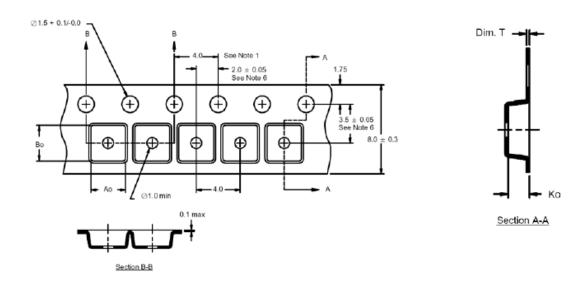
NOTES:

- 1. Material: Antistatic Plastic (High Impact Polystyrene)
- 2.
- Shelf Life: 2 years Color: White (Blue for special) 3.

Application	Α	W	Tape Width	Н	Т	
SOIC-8	330±2	12.4	12	100±2	2.5±0.5	
SOT-23	172±2 8.4	9.4	55±2	2±1		
TSOP-6	172±2	0.4	8.4	55±2	2±1	

Tape & Reel Information

TSOP-6



NOTES:

- 1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
- 2. Camber not to exceed 1 mm in 100 mm.
- 3. Material: Conductive black Advantek polystyrene.
- 4. As and Bo measured on a plane 0.3 mm above the bottom of the pocket except for 3M carrier tape.
- 5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
- 7. All sizes in mm unless specified.
- 8. Tolerances unless specified will be \pm 0.1 mm.

QUANTITY	PER REEL
T1	3,000

Ao = 3.15 mm Bo = 3.20 mm Ko = 1.40 mm